

S6602

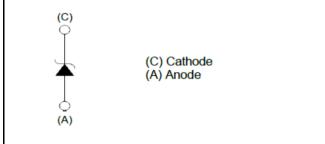
SiC Schottky Barrier Diode Bare Die

V_R	1200V
I _F	10A ^{*1}
Q_{C}	36nC

Features

- 1) Low forward voltage
- 2) Negligible recovery time/current
- 3) Temperature independent switching behavior
- 4) High surge current capability

●Inner circuit



Applications

- Switch Mode Power Supply
- Uninterruptible Power Supply
- Solar Inverter
- Motor Drive
- Air Conditioner
- EV Charger

● **Absolute maximum ratings** (T_{vj} = 25°C unless otherwise specified)

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Parameter		Symbol	Value	Unit	
Reverse voltage (repetitive peak)		V_{RM}	1200	V	
Reverse voltage (DC)		V_R	1200	V	
Continuous forward current		I _F	10 ^{*1}	А	
Surge non- repetitive forward current	PW=10ms sinusoidal, T _{vj} =25°C	I _{FSM} *2	100	Α	
	PW=10ms sinusoidal, T _{vj} =150°C		80	А	
	PW=10μs square, T _{vj} =25°C		420	А	
2	PW=10ms, T _{vj} =25°C	$\int i^2 dt$	57	A ² s	
i ² t value	PW=10ms, T _{vj} =150°C	j Jiřát	32	A ² s	
Virtual junction temperature		T_{vj}	175	°C	
Range of storage temperature		T _{stg}	-55 to +175	°C	

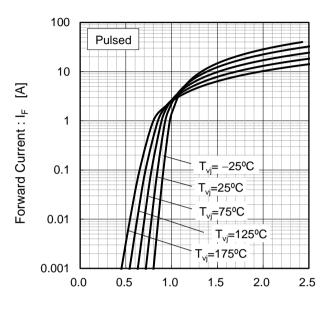
^{*1} Limited by maximum T_{vj} *2 In case of TO-220AC package using alminum wire 400 μ m in diameter and Z_{thJC} of 0.76 °C/W or less (PW = 10ms).

•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			11.2
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =40μA	1200	-	-	V
	V _F	I _F =10A,T _{vj} =25°C	-	1.4	1.6	V
Forward voltage		I _F =10A,T _{vj} =150°C	-	1.8	-	V
		I _F =10A,T _{vj} =175°C	-	2.0	-	V
Reverse current	I _R	V _R =1200V,T _{vj} =25°C	-	0.1	40	μΑ
		V _R =1200V,T _{vj} =150°C	-	7	-	μА
		V _R =1200V,T _{vj} =175°C	-	20	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	520	-	pF
		V _R =1200V,f=1MHz	-	37	-	pF
Total capacitive charge	Q_{C}	V _R =800V,di/dt=500A/μs	-	36	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	17	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	210	-	mJ

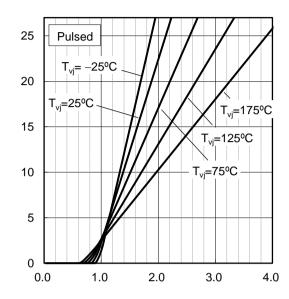
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



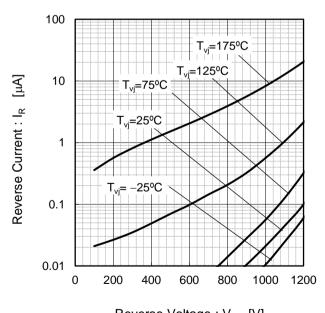
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



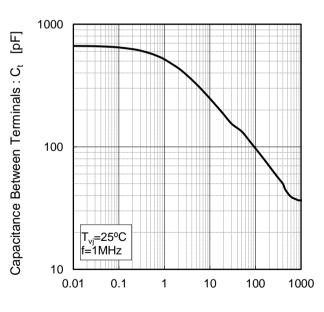
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics

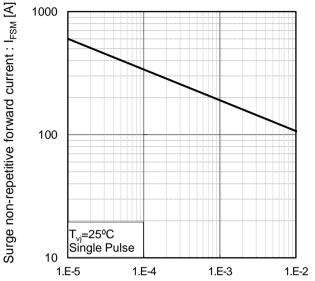


Reverse Voltage : V_R [V]

Forward Current: I_F

Electrical characteristic curves

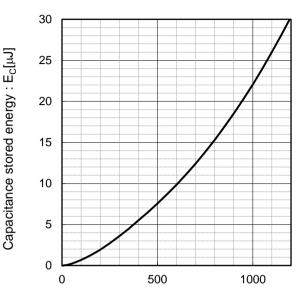
Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)*



Pulse Width: PW [s]

 * Assumes Z_{thJC} of 0.76 $^{\circ}\text{C/W}$ or less. (Pulse Width = 10ms)

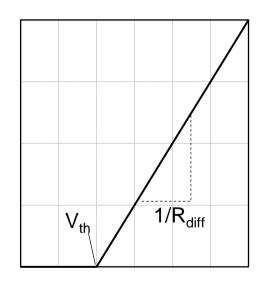
Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

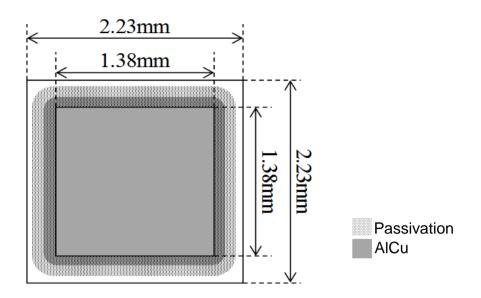
$$V_{th} (T_{vj}) = a_0 + a_1 T_{vj}$$

 $R_{diff} (T_{vj}) = b_0 + b_1 T_{vj} + b_2 T_{vj}^2$

Symbol	Typical Value	Unit
a ₀	0.922	V
a ₁	-1.388	mV/°C
b ₀	42.40	mΩ
b ₁	0.259	mΩ/°C
b ₂	1.341	μΩ/°C²

 T_{v_j} in °C; -55 °C < T_{v_j} <175 °C ; I_F < 20 A

Forward Current: IF



Mechanical Parameters

S6602TSCF

Die Size	2.23mm × 2.23mm (Including Scribe Width)
Thickness	235 ± 35 μm
Anode Pad Size	1.38mm × 1.38mm

Wafer Size	100mm
Topside Metallization	AlCu
Backside Metallization	Ti-Ni(1.2μm)-Au(70nm)-Ag(0.3μm)
Passivation	Polybenzoxazole

S6602MTFCZ

Die Size	2.23mm × 2.23mm (Including Scribe Width)
Thickness	235 ± 35 μm
Anode Pad Size	1.38mm × 1.38mm

Wafer Size	150mm
Topside Metallization	AlCu
Backside Metallization	Ti-Ni(1.2μm)-Au(70nm)
Passivation	Polyimide

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